

NCE N-Channel Super Trench Power MOSFET

Description

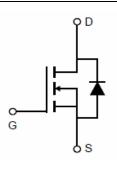
The NCEP30T15GU uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{\text{DS}(\text{ON})}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

General Features

- V_{DS} =30V, I_D =150A $R_{DS(ON)}$ =1.5m Ω (typical) @ V_{GS} =10V $R_{DS(ON)}$ =2.0m Ω (typical) @ V_{GS} =4.5V
- Excellent gate charge x R_{DS(on)} product(FOM)
- Very low on-resistance R_{DS(on)}
- 150 °C operating temperature
- Pb free terminal plating
- RoHS compliant
- Halogen free

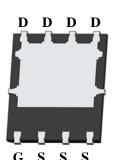
Application

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification









Top View

Bottom View

100% UIS TESTED! 100% ΔVds TESTED!

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
P30T15GU	NCEP30T15GU	DFN5X6-8L	-	-	-

Absolute Maximum Ratings (T_c=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	30	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous (Silicon Limited)	I _D	150	А
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	120	Α
Pulsed Drain Current (Package Limited)	I _{DM}	340	А
Maximum Power Dissipation	P _D	85	W
Derating factor		0.68	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	650	mJ
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 150	$^{\circ}\!\mathbb{C}$

Thermal Characteristic

Thermal Resistance,Junction-to-Case ^(Note 2)	$R_{ heta JC}$	1.47	°C/W	
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Electrical Characteristics (T_C=25°C unless otherwise noted)

Parameter	Symbol Condition		Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	30		-	V
Zoro Coto Voltago Drain Current	, T _J =25℃	\/ -20\/\/ -0\/	-	-	1	μA
Zero Gate Voltage Drain Current	I _{DSS} T _J =55℃	V_{DS} =30V, V_{GS} =0V	-	-	1.5	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1.2	1.7	2.2	V
Drain-Source On-State Resistance	5	V _{GS} =10V, I _D =75A	-	1.5	1.9	mΩ
Dialii-Source Off-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =75A	-	2.0	2.5	mΩ
Forward Transconductance	g FS	V _{DS} =5V,I _D =75A		65	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}	\/ -45\/\/ -0\/	-	3372	-	PF
Output Capacitance	C _{oss}	V_{DS} =15V, V_{GS} =0V, F=1.0MHz	-	902	-	PF
Reverse Transfer Capacitance	C _{rss}	F-1.UIVITIZ	-	60	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}		-	7	-	nS
Turn-on Rise Time	t _r	V _{DD} =15V,I _D =75A	-	5	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10 V , R_{G} =1.6 Ω	-	32	-	nS
Turn-Off Fall Time	t _f		-	9	-	nS
Total Gate Charge	Qg	V _{DS} =15V,I _D =75A,	-	55	-	nC
Gate-Source Charge	Q _{gs}	$V_{DS} = 15V, I_D = 75A,$ $V_{GS} = 10V$	-	9		nC
Gate-Drain Charge	Q_{gd}	V _{GS} -10V	-	8.5		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =75A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	150	Α
Reverse Recovery Time	t _{rr}	$T_J = 25^{\circ}C, I_F = I_S$	-		26	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-		95	nC

Notes:

- ${\it 1. Repetitive Rating: Pulse width limited by maximum junction temperature.}\\$
- 2. Surface Mounted on FR4 Board, $t \leq 10 \; \text{sec.}$
- 3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25 $^{\circ}\text{C}$,V_DD=15V,V_G=10V,L=0.5mH,Rg=25 Ω



Typical Electrical and Thermal Characteristics

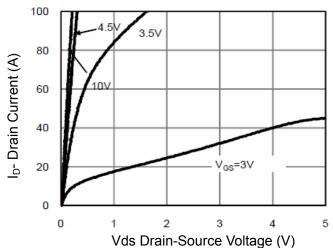


Figure 1 Output Characteristics

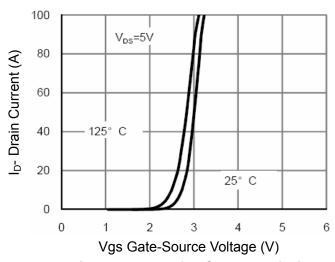


Figure 2 Transfer Characteristics

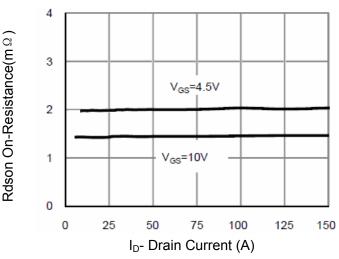


Figure 3 Rdson- Drain Current

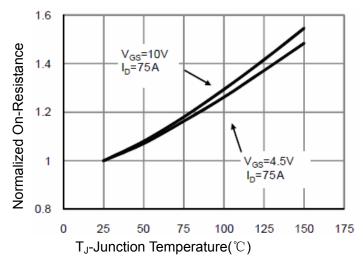


Figure 4 Rdson-Junction Temperature

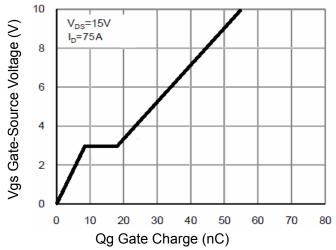


Figure 5 Gate Charge

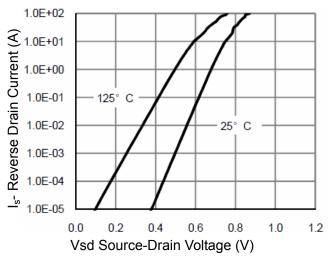


Figure 6 Source- Drain Diode Forward



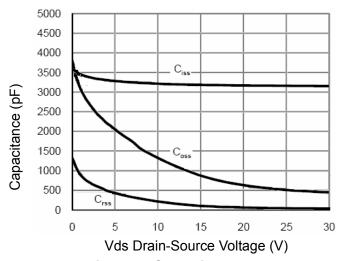


Figure 7 Capacitance vs Vds

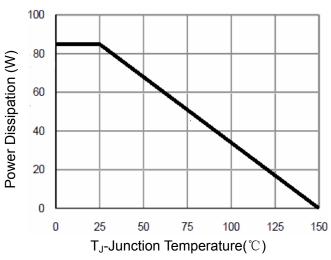


Figure 9 Power De-rating

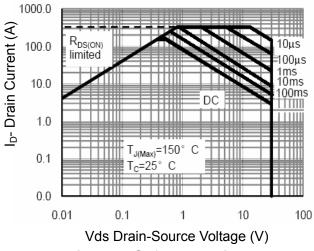


Figure 8 Safe Operation Area

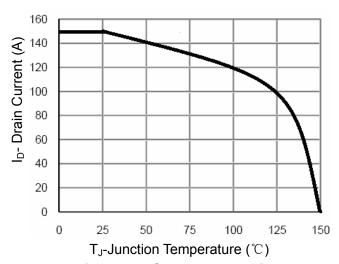


Figure 10 Current De-rating

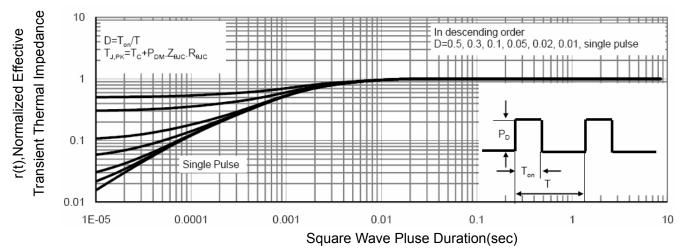
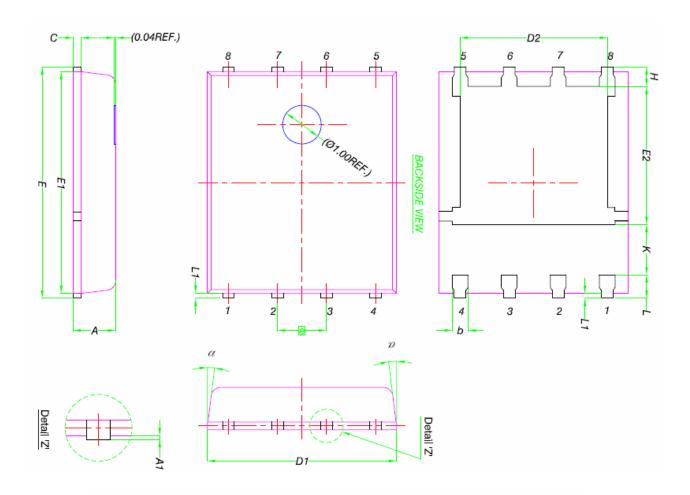


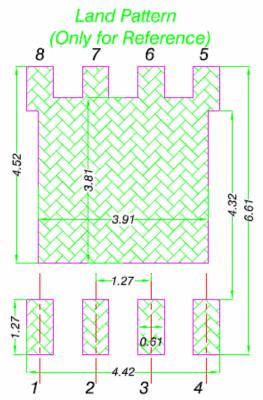
Figure 11 Normalized Maximum Transient Thermal Impedance



DFN5X6-8L Package Information



544	MILLIMETERS				
DIM.	MIN. NOM.		MAX.		
Α	0.90	1.00	1.10		
A1	0	-	0.05		
b	0.33	0.41	0.51		
С	0.20	0.25	0.30		
D1	4.80	4.90	5.00		
D2	3.61	3.81	3.96		
Ε	5.90	6.00	6.10		
E1	5.70	5.75	5.80		
E2	3.38	3.58	3.78		
е	1.27 BSC				
Н	0.41	0.51	0.61		
K	1.10	-	-		
L	0.51	0.61	0.71		
L1	0.06	0.13	0.20		
α	<i>0</i> °	-	12°		



NCEP30T15GU

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